Renesas Electronics America Inc - M306N4MGT-168FPUSQ Datasheet

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	M16C/60
Core Size	16-Bit
Speed	20MHz
Connectivity	CANbus, I²C, IEBus, SIO, UART/USART
Peripherals	DMA, WDT
Number of I/O	87
Program Memory Size	256KB (256K x 8)
Program Memory Type	Mask ROM
EEPROM Size	-
RAM Size	10K x 8
Voltage - Supply (Vcc/Vdd)	4.2V ~ 5.5V
Data Converters	A/D 26x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-BQFP
Supplier Device Package	100-QFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/m306n4mgt-168fpusq

1.2 Performance Overview

Table 1.1 lists the Functions and Specifications for M16C/6N Group (M16C/6N4).

Table 1.1 Functions and Specifications for M16C/6N Group (M16C/6N4)

Item			Specification	
			Normal-ver.	T/V-ver.
CPU	Number of fundamental instructions		91 instructions	
	Minimum instruction execution time		41.7 ns (f(BCLK) = 24 MHz, 1/1 prescaler, without software wait)	50.0 ns (f(BCLK) = 20 MHz, 1/1 prescaler, without software wait)
	Operating mode		Single-chip, memory expansion, and microprocessor modes	
	Address space		1 Mbyte	
	Memory capacity		Refer to **Table 1.2 Product Information**	
Peripheral Function	Ports		Input/Output: 87 pins, Input: 1 pin	
	Multifunction timers		Timer A: 16 bits × 5 channels Timer B: 16 bits × 6 channels Three-phase motor control circuit	
	Serial interfaces		3 channels Clock synchronous, UART, I²C-bus (1), IEBus (2) 1 channel Clock synchronous	
	A/D converter		10-bit A/D converter: 1 circuit, 26 channels	
	D/A converter		8 bits × 2 channels	
	DMAC		2 channels	
	CRC calculation circuit		CRC-CCITT	
	CAN module		2 channels with 2.0B specification	
	Watchdog timer		15 bits × 1 channel (with prescaler)	
	Interrupts		Internal: 31 sources, External: 9 sources Software: 4 sources, Priority levels: 7 levels	
	Clock generation circuits		4 circuits • Main clock oscillation circuit (*) • Sub clock oscillation circuit (*) • On-chip oscillator • PLL frequency synthesizer (*) Equipped with on-chip feedback resistor	
	Oscillation-stopped detector		Main clock oscillation stop and re-oscillation detection function	
Electrical Characteristics	Supply voltage		VCC = 3.0 to 5.5 V (f(BCLK) = 24 MHz, 1/1 prescaler, without software wait)	VCC = 4.2 to 5.5 V (f(BCLK) = 20 MHz, 1/1 prescaler, without software wait)
	Consumption current	Mask ROM	20 mA (f(BCLK) = 24 MHz, PLL operation, no division)	18 mA (f(BCLK) = 20 MHz, PLL operation, no division)
		Flash memory	22 mA (f(BCLK) = 24 MHz, PLL operation, no division)	20 mA (f(BCLK) = 20 MHz, PLL operation, no division)
		Mask ROM	3 µA (f(BCLK) = 32 kHz, Wait mode, Oscillation capacity Low)	
		Flash memory	0.8 µA (Stop mode, Topr = 25°C)	
Flash Memory Version	Programming and erasure voltage		3.0 ± 0.3 V or 5.0 ± 0.5 V	5.0 ± 0.5 V
	Programming and erasure endurance		100 times	
I/O Characteristics	I/O withstand voltage		5.0 V	
	Output current		5 mA	
Operating Ambient Temperature			-40 to 85°C	T version: -40 to 85°C V version: -40 to 125°C (option)
Device Configuration			CMOS high-performance silicon gate	
Package			100-pin molded-plastic QFP, LQFP	

NOTES:
1. I²C-bus is a trademark of Koninklijke Philips Electronics N.V.
2. IEBus is a trademark of NEC Electronics Corporation.

option: All options are on request basis.

Table 1.3 List of Pin Names (1)

Pin No.		Control Pin	Port	Interrupt Pin	Timer Pin	UART Pin	Analog Pin	CAN Module Pin	Bus Control Pin
FP	GP								
1	99		P9_6				ANEX1	CTX0	
2	100		P9_5				ANEX0	CRX0	
3	1		P9_4		TB4IN		DA1		
4	2		P9_3		TB3IN		DA0		
5	3		P9_2		TB2IN	SOUT3			
6	4		P9_1		TB1IN	SIN3			
7	5		P9_0		TB0IN	CLK3			
8	6	BYTE							
9	7	CNVSS							
10	8	XCIN	P8_7						
11	9	XCOUT	P8_6						
12	10	$\overline{\text{RESET}}$							
13	11	XOUT							
14	12	VSS							
15	13	XIN							
16	14	VCC1							
17	15		P8_5	$\overline{\text{NMI}}$					
18	16		P8_4	$\overline{\text{INT2}}$	ZP				
19	17		P8_3	INT1					
20	18		P8_2	INT0					
21	19		P8_1		TA4IN/$\overline{\text{U}}$				
22	20		P8_0		TA4OUT/U				
23	21		P7_7		TA3IN			CRX1	
24	22		P7_6		TA3OUT			CTX1	
25	23		P7_5		TA2IN/$\overline{\text{W}}$				
26	24		P7_4		TA2OUT/W				
27	25		P7_3		TA1IN/$\overline{\text{V}}$	$\overline{\text{CTS2}}$/$\overline{\text{RTS2}}$			
28	26		P7_2		TA1OUT/V	CLK2			
29	27		P7_1		TA0IN/TB5IN	RXD2/SCL2			
30	28		P7_0		TA0OUT	TXD2/SDA2			
31	29		P6_7			TXD1/SDA1			
32	30		P6_6			RXD1/SCL1			
33	31		P6_5			CLK1			
34	32		P6_4			$\overline{\text{CTS1}}$/$\overline{\text{RTS1}}$/$\overline{\text{CTS0}}$/CLKS1			
35	33		P6_3			TXD0/SDA0			
36	34		P6_2			RXD0/SCL0			
37	35		P6_1			CLK0			
38	36		P6_0			$\overline{\text{CTS0}}$/$\overline{\text{RTS0}}$			
39	37		P5_7						$\overline{\text{RDY}}$/CLKOUT
40	38		P5_6						ALE
41	39		P5_5						$\overline{\text{HOLD}}$
42	40		P5_4						$\overline{\text{HLDA}}$
43	41		P5_3						BCLK
44	42		P5_2						$\overline{\text{RD}}$
45	43		P5_1						$\overline{\text{WRH}}$/$\overline{\text{BHE}}$
46	44		P5_0						$\overline{\text{WRL}}$/$\overline{\text{WR}}$
47	45		P4_7						$\overline{\text{CS3}}$
48	46		P4_6						$\overline{\text{CS2}}$
49	47		P4_5						$\overline{\text{CS1}}$
50	48		P4_4						$\overline{\text{CS0}}$

FP: PRQP0100JB-A (100P6S-A), GP: PLQP0100KB-A (100P6Q-A)

1.6 Pin Functions

Tables 1.5 to 1.7 list the Pin Functions.

Table 1.5 Pin Functions (1)

Signal Name	Pin Name	I/O Type	Description
Power supply input	VCC1, VCC2, VSS	I	Apply 4.2 to 5.5 V (T/V-ver.), 3.0 to 5.5 V (Normal-ver.) to the VCC1 and VCC2 pins and 0 V to the VSS pin. The VCC apply condition is that VCC2 = VCC1 (1).
Analog power supply input	AVCC, AVSS	I	Applies the power supply for the A/D converter. Connect the AVCC pin to VCC1. Connect the AVSS pin to VSS.
Reset input	RESET	I	The MCU is in a reset state when applying "L" to the this pin.
CNVSS	CNVSS	I	Switches processor mode. Connect this pin to VSS to when after a reset to start up in single-chip mode. Connect this pin to VCC1 to start up in microprocessor mode.
External data bus width select input	BYTE	I	Switches the data bus in external memory space. The data bus is 16-bit long when the this pin is held "L" and 8-bit long when the this pin is held "H". Set it to either one. Connect this pin to VSS when single-chip mode.
Bus control pins	D0 to D7	I/O	Inputs and outputs data (D0 to D7) when these pins are set as the separate bus.
	D8 to D15	I/O	Inputs and outputs data (D8 to D15) when external 16-bit data bus is set as the separate bus.
	A0 to A19	O	Output address bits (A0 to A19).
	A0/D0 to A7/D7	I/O	Input and output data (D0 to D7) and output address bits (A0 to A7) by time-sharing when external 8-bit data bus are set as the multiplexed bus.
	A1/D0 to A8/D7	I/O	Input and output data (D0 to D7) and output address bits (A1 to A8) by time-sharing when external 16-bit data bus are set as the multiplexed bus.
	$\overline{CS0}$ to $\overline{CS3}$	O	Output $\overline{CS0}$ to $\overline{CS3}$ signals. $\overline{CS0}$ to $\overline{CS3}$ are chip-select signals to specify an external space.
	$\overline{WRL}$/$\overline{WR}$ $\overline{WRH}$/$\overline{BHE}$ $\overline{RD}$	O	Output $\overline{WRL}$, $\overline{WRH}$, ($\overline{WR}$, $\overline{BHE}$), $\overline{RD}$ signals. $\overline{WRL}$ and $\overline{WRH}$ or $\overline{BHE}$, and $\overline{WR}$ can be switched by program. • $\overline{WRL}$, $\overline{WRH}$, and $\overline{RD}$ are selected The $\overline{WRL}$ signal becomes "L" by writing data to an even address in an external memory space. The $\overline{WRH}$ signal becomes "L" by writing data to an odd address in an external memory space. The $\overline{RD}$ pin signal becomes "L" by reading data in an external memory space. • $\overline{WR}$, $\overline{BHE}$, and $\overline{RD}$ are selected The $\overline{WR}$ signal becomes "L" by writing data in an external memory space. The $\overline{RD}$ signal becomes "L" by reading data in an external memory space. The $\overline{BHE}$ signal becomes "L" by accessing an odd address. Select $\overline{WR}$, $\overline{BHE}$, and $\overline{RD}$ for an external 8-bit data bus.
	ALE	O	ALE is a signal to latch the address.
	HOLD	I	While the $\overline{HOLD}$ pin is held "L", the MCU is placed in a hold state.
	$\overline{HLDA}$	O	In a hold state, $\overline{HLDA}$ outputs a "L" signal.
	$\overline{RDY}$	I	While applying a "L" signal to the $\overline{RDY}$ pin, the MCU is placed in a wait state.

I: Input O: Output I/O: Input/Output

NOTE:
1. In this manual, hereafter, VCC refers to VCC1 unless otherwise noted.

Table 4.5 SFR Information (5)

Address	Register	Symbol	After Reset
0100h	CAN0 Message Box 10: Identifier / DLC		XXh
0101h			XXh
0102h			XXh
0103h			XXh
0104h			XXh
0105h			XXh
0106h	CAN0 Message Box 10: Data Field		XXh
0107h			XXh
0108h			XXh
0109h			XXh
010Ah			XXh
010Bh			XXh
010Ch			XXh
010Dh			XXh
010Eh	CAN0 Message Box 10: Time Stamp		XXh
010Fh			XXh
0110h	CAN0 Message Box 11: Identifier / DLC		XXh
0111h			XXh
0112h			XXh
0113h			XXh
0114h			XXh
0115h			XXh
0116h	CAN0 Message Box 11: Data Field		XXh
0117h			XXh
0118h			XXh
0119h			XXh
011Ah			XXh
011Bh			XXh
011Ch			XXh
011Dh			XXh
011Eh	CAN0 Message Box 11: Time Stamp		XXh
011Fh			XXh
0120h	CAN0 Message Box 12: Identifier / DLC		XXh
0121h			XXh
0122h			XXh
0123h			XXh
0124h			XXh
0125h			XXh
0126h	CAN0 Message Box 12: Data Field		XXh
0127h			XXh
0128h			XXh
0129h			XXh
012Ah			XXh
012Bh			XXh
012Ch			XXh
012Dh			XXh
012Eh	CAN0 Message Box 12: Time Stamp		XXh
012Fh			XXh
0130h	CAN0 Message Box 13: Identifier / DLC		XXh
0131h			XXh
0132h			XXh
0133h			XXh
0134h			XXh
0135h			XXh
0136h	CAN0 Message Box 13: Data Field		XXh
0137h			XXh
0138h			XXh
0139h			XXh
013Ah			XXh
013Bh			XXh
013Ch			XXh
013Dh			XXh
013Eh	CAN0 Message Box 13: Time Stamp		XXh
013Fh			XXh

X: Undefined

Table 4.8 SFR Information (8) (1)

Address	Register	Symbol	After Reset
01C0h	Timer B3, B4, B5 Count Start Flag	TBSR	000XXXXXb
01C1h			
01C2h	Timer A1-1 Register	TA11	XXh
01C3h			XXh
01C4h	Timer A2-1 Register	TA21	XXh
01C5h			XXh
01C6h	Timer A4-1 Register	TA41	XXh
01C7h			XXh
01C8h	Three-Phase PWM Control Register 0	INVC0	00h
01C9h	Three-Phase PWM Control Register 1	INVC1	00h
01CAh	Three-Phase Output Buffer Register 0	IDB0	00111111b
01CBh	Three-Phase Output Buffer Register 1	IDB1	00111111b
01CCh	Dead Time Timer	DTT	XXh
01CDh	Timer B2 Interrupt Generation Frequency Set Counter	ICTB2	XXh
01CEh			
01CFh			
01D0h	Timer B3 Register	TB3	XXh
01D1h			XXh
01D2h	Timer B4 Register	TB4	XXh
01D3h			XXh
01D4h	Timer B5 Register	TB5	XXh
01D5h			XXh
01D6h			
01D7h			
01D8h			
01D9h			
01DAh			
01DBh	Timer B3 Mode Register	TB3MR	00XX0000b
01DCh	Timer B4 Mode Register	TB4MR	00XX0000b
01DDh	Timer B5 Mode Register	TB5MR	00XX0000b
01DEh	Interrupt Source Select Register 0	IFSR0	00XXX000b
01DFh	Interrupt Source Select Register 1	IFSR1	00h
01E0h	SI/O3 Transmit/Receive Register	S3TRR	XXh
01E1h			
01E2h	SI/O3 Control Register	S3C	01000000b
01E3h	SI/O3 Bit Rate Register	S3BRG	XXh
01E4h			
01E5h			
01E6h			
01E7h			
01E8h			
01E9h			
01EAh			
01EBh			
01ECh	UART0 Special Mode Register 4	U0SMR4	00h
01EDh	UART0 Special Mode Register 3	U0SMR3	000X0X0Xb
01EEh	UART0 Special Mode Register 2	U0SMR2	X0000000b
01EFh	UART0 Special Mode Register	U0SMR	X0000000b
01F0h	UART1 Special Mode Register 4	U1SMR4	00h
01F1h	UART1 Special Mode Register 3	U1SMR3	000X0X0Xb
01F2h	UART1 Special Mode Register 2	U1SMR2	X0000000b
01F3h	UART1 Special Mode Register	U1SMR	X0000000b
01F4h	UART2 Special Mode Register 4	U2SMR4	00h
01F5h	UART2 Special Mode Register 3	U2SMR3	000X0X0Xb
01F6h	UART2 Special Mode Register 2	U2SMR2	X0000000b
01F7h	UART2 Special Mode Register	U2SMR	X0000000b
01F8h	UART2 Transmit/Receive Mode Register	U2MR	00h
01F9h	UART2 Bit Rate Register	U2BRG	XXh
01FAh	UART2 Transmit Buffer Register	U2TB	XXh
01FBh			XXh
01FCh	UART2 Transmit/Receive Control Register 0	U2C0	00001000b
01FDh	UART2 Transmit/Receive Control Register 1	U2C1	00000010b
01FEh	UART2 Receive Buffer Register	U2RB	XXh
01FFh			XXh

X: Undefined

NOTE:
1. Blank spaces are reserved. No access is allowed.

Table 5.2 Recommended Operating Conditions (1) [1]

Symbol	Parameter		Standard			Unit
			Min.	Typ.	Max.	
V_{CC}	Supply voltage (VCC1 = VCC2)		4.2	5.0	5.5	V
AV_{CC}	Analog supply voltage			V_{CC}		V
V_{SS}	Supply voltage			0		V
AV_{SS}	Analog supply voltage			0		V
V_{IH}	HIGH input voltage	P3_1 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0, P7_2 to P7_7, P8_0 to P8_7, P9_0, P9_2 to P9_7, P10_0 to P10_7, XIN, $\overline{RESET}$, CNVSS, BYTE	0.8 V_{CC}		V_{CC}	V
		P7_1, P9_1	0.8 V_{CC}		6.5	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 (During single-chip mode)	0.8 V_{CC}		V_{CC}	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 (Data input during memory expansion and microprocessor modes)	0.5 V_{CC}		V_{CC}	V
V_{IL}	LOW input voltage	P3_1 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0 to P7_7, P8_0 to P8_7, P9_0 to P9_7, P10_0 to P10_7, XIN, $\overline{RESET}$, CNVSS, BYTE	0		0.2 V_{CC}	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 (During single-chip mode)	0		0.2 V_{CC}	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 (Data input during memory expansion and microprocessor modes)	0		0.16 V_{CC}	V
$I_{OH(peak)}$	HIGH peak output current	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0, P7_2 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0, P9_2 to P9_7, P10_0 to P10_7			–10.0	mA
$I_{OH(avg)}$	HIGH average output current	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0, P7_2 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0, P9_2 to P9_7, P10_0 to P10_7			–5.0	mA
$I_{OL(peak)}$	LOW peak output current	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0 to P9_7, P10_0 to P10_7			10.0	mA
$I_{OL(avg)}$	LOW average output current	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0 to P9_7, P10_0 to P10_7			5.0	mA

NOTES:
1. Referenced to VCC = 4.2 to 5.5 V at Topr = –40 to 85°C unless otherwise specified.
2. Average output current values during 100 ms period.
3. The total $I_{OL(peak)}$ for ports P0, P1, P2, P8_6, P8_7, P9, and P10 must be 80 mA max.
   The total $I_{OL(peak)}$ for ports P3, P4, P5, P6, P7, and P8_0 to P8_4 must be 80 mA max.
   The total $I_{OH(peak)}$ for ports P0, P1, and P2 must be –40 mA max.
   The total $I_{OH(peak)}$ for ports P3, P4, and P5 must be –40 mA max.
   The total $I_{OH(peak)}$ for ports P6, P7, and P8_0 to P8_4 must be –40 mA max.
   The total $I_{OH(peak)}$ for ports P8_6, P8_7, P9, and P10 must be –40 mA max.

Table 5.5 Electrical Characteristics (2) [1]

Symbol	Parameter		Measuring Condition		Standard			Unit
					Min.	Typ.	Max.	
I_{CC}	Power supply current (VCC = 4.2 to 5.5 V)	In single-chip mode, the output pins are open and other pins are VSS.	Mask ROM	f(BCLK) = 20 MHz, PLL operation, No division		18	32	mA
				On-chip oscillation, No division		1		mA
			Flash memory	f(BCLK) = 20 MHz, PLL operation, No division		20	34	mA
				On-chip oscillation, No division		1.8		mA
			Flash memory program	f(BCLK) = 10 MHz, VCC = 5 V		15		mA
			Flash memory erase	f(BCLK) = 10 MHz, VCC = 5 V		25		mA
			Mask ROM	f(BCLK) = 32kHz, Low power dissipation mode, ROM [2]		25		µA
			Flash memory	f(BCLK) = 32 kHz, Low power dissipation mode, RAM [2]		25		µA
				f(BCLK) = 32 kHz, Low power dissipation mode, Flash memory [2]		420		µA
			Mask ROM Flash memory	On-chip oscillation, Wait mode		50		µA
				f(BCLK) = 32 kHz, Wait mode [3], Oscillation capacity High		8.5		µA
				f(BCLK) = 32 kHz, Wait mode [3], Oscillation capacity Low		3.0		µA
				Stop mode, Topr = 25°C		0.8	3.0	µA

NOTES:
1. Referenced to VCC = 4.2 to 5.5 V, VSS = 0 V at Topr = –40 to 85°C, f(BCLK) = 20 MHz unless otherwise specified.
2. This indicates the memory in which the program to be executed exists.
3. With one timer operated using fC32.

Table 5.8 Power Supply Circuit Timing Characteristics

Symbol	Parameter	Measuring Condition	Standard			Unit
			Min.	Typ.	Max.	
$t_{d(P-R)}$	Time for internal power supply stabilization during powering-on	VCC = 4.2 to 5.5 V			2	ms
$t_{d(R-S)}$	STOP release time				150	µs
$t_{d(W-S)}$	Low power dissipation mode wait mode release time				150	µs

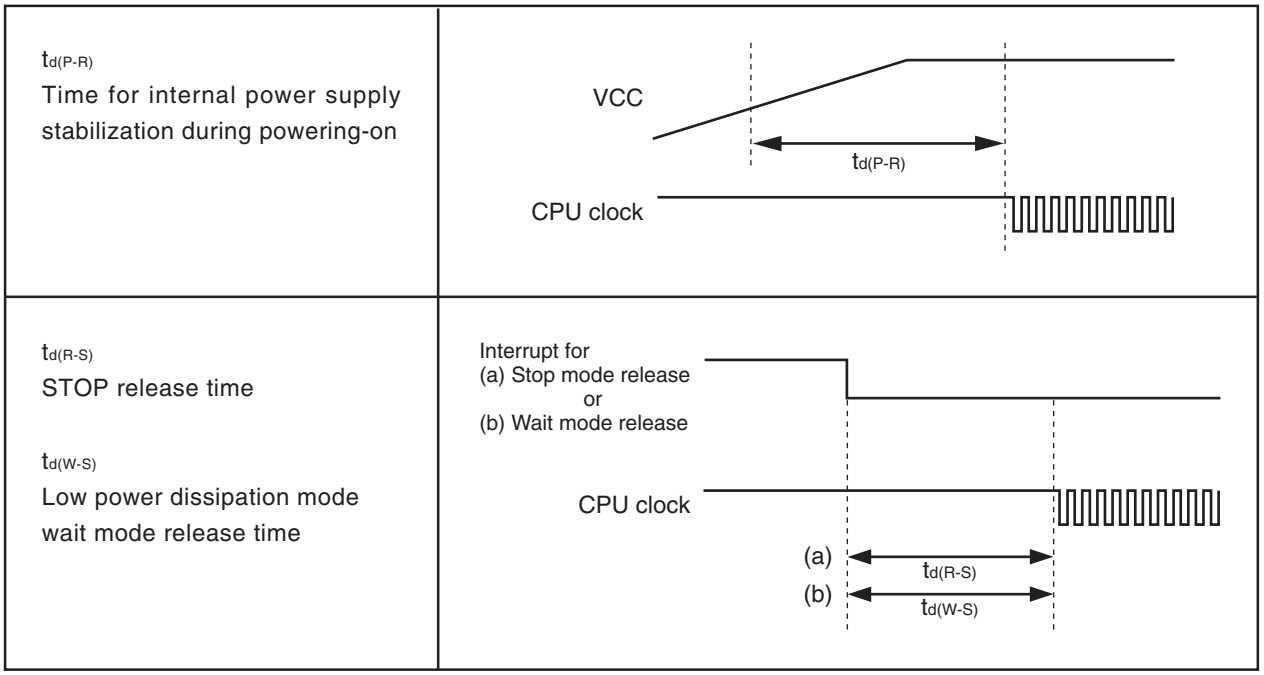


Figure 5.1 Power Supply Circuit Timing Diagram

Timing Requirements

VCC = 5 V

(Referenced to VCC = 5 V, VSS = 0 V, at Topr = –40 to 85°C unless otherwise specified)

Table 5.17 Timer B Input (Counter Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN input cycle time (counted on one edge)	100		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width (counted on one edge)	40		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width (counted on one edge)	40		ns
$t_{c(TB)}$	TBiIN input cycle time (counted on both edges)	200		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width (counted on both edges)	80		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width (counted on both edges)	80		ns

Table 5.18 Timer B Input (Pulse Period Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN input cycle time	400		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width	200		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width	200		ns

Table 5.19 Timer B Input (Pulse Width Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN input cycle time	400		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width	200		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width	200		ns

Table 5.20 A/D Trigger Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(AD)}$	$\overline{\text{ADTRG}}$ input cycle time (trigger able minimum)	1000		ns
$t_{w(ADL)}$	$\overline{\text{ADTRG}}$ input LOW pulse width	125		ns

Table 5.21 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi input cycle time	200		ns
$t_{w(CKH)}$	CLKi input HIGH pulse width	100		ns
$t_{w(CKL)}$	CLKi input LOW pulse width	100		ns
$t_{d(C-Q)}$	TXDi output delay time		80	ns
$t_{h(C-Q)}$	TXDi hold time	0		ns
$t_{su(D-C)}$	RXDi input setup time	70		ns
$t_{h(C-D)}$	RXDi input hold time	90		ns

Table 5.22 External Interrupt $\overline{\text{INTi}}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	$\overline{\text{INTi}}$ input HIGH pulse width	250		ns
$t_{w(INL)}$	$\overline{\text{INTi}}$ input LOW pulse width	250		ns

Switching Characteristics VCC = 5 V

(Referenced to VCC = 5 V, VSS = 0 V, at Topr = –40 to 85 °C unless otherwise specified)

Table 5.23 Memory Expansion Mode and Microprocessor Mode (for setting with no wait)

Symbol	Parameter	Measuring Condition	Standard		Unit
			Min.	Max.	
$t_{d(BCLK-AD)}$	Address output delay time	Figure 5.2		25	ns
$t_{h(BCLK-AD)}$	Address output hold time (in relation to BCLK)		4		ns
$t_{h(RD-AD)}$	Address output hold time (in relation to RD)		0		ns
$t_{h(WR-AD)}$	Address output hold time (in relation to WR)		(NOTE 1)		ns
$t_{d(BCLK-CS)}$	Chip select output delay time			25	ns
$t_{h(BCLK-CS)}$	Chip select output hold time (in relation to BCLK)		4		ns
$t_{d(BCLK-ALE)}$	ALE signal output delay time			15	ns
$t_{h(BCLK-ALE)}$	ALE signal output hold time		–4		ns
$t_{d(BCLK-RD)}$	RD signal output delay time			25	ns
$t_{h(BCLK-RD)}$	RD signal output hold time		0		ns
$t_{d(BCLK-WR)}$	WR signal output delay time			25	ns
$t_{h(BCLK-WR)}$	WR signal output hold time		0		ns
$t_{d(BCLK-DB)}$	Data output delay time (in relation to BCLK)			40	ns
$t_{h(BCLK-DB)}$	Data output hold time (in relation to BCLK) (3)		4		ns
$t_{d(DB-WR)}$	Data output delay time (in relation to WR)		(NOTE 2)		ns
$t_{h(WR-DB)}$	Data output hold time (in relation to WR) (3)		(NOTE 1)		ns
$t_{d(BCLK-HLDA)}$	$\overline{HLDA}$ output delay time			40	ns

NOTES:

1. Calculated according to the BCLK frequency as follows:

$$\frac{0.5 \times 10^9}{f(BCLK)} - 10 \text{ [ns]}$$

2. Calculated according to the BCLK frequency as follows:

$$\frac{0.5 \times 10^9}{f(BCLK)} - 40 \text{ [ns]}$$ f(BCLK) is 12.5 MHz or less.

3. This standard value shows the timing when the output is off, and does not show hold time of data bus.
   Hold time of data bus varies with capacitor volume and pull-up (pull-down) resistance value.
   Hold time of data bus is expressed in
   $t = -CR \times \ln (1 - V_{OL} / V_{CC})$
   by a circuit of the right figure.
   For example, when $V_{OL} = 0.2\ V_{CC}$, C = 30 pF, R =1 kΩ, hold time of output "L" level is
   $t = -30\text{ pF} \times 1\text{ k}\Omega \times \ln (1 - 0.2\ V_{CC} / V_{CC}) = 6.7$ ns.

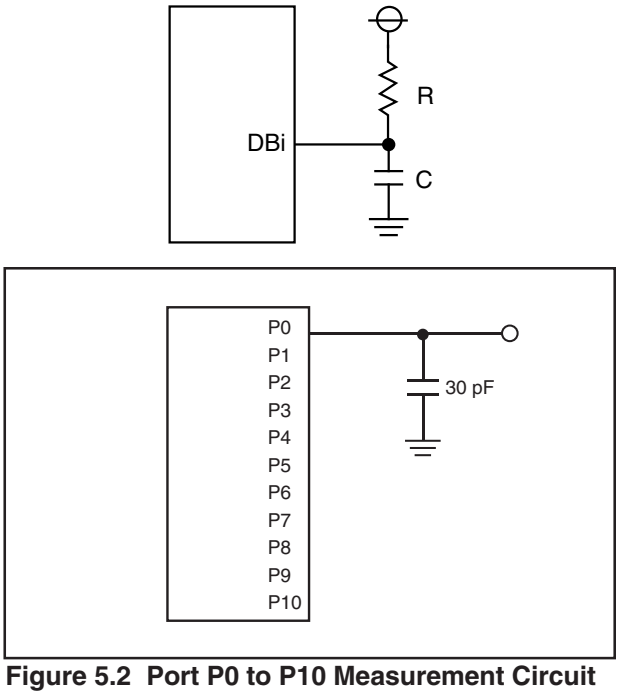


Figure 5.2 Port P0 to P10 Measurement Circuit

Switching Characteristics

VCC = 5 V

(Referenced to VCC = 5 V, VSS = 0 V, at Topr = –40 to 85 °C unless otherwise specified)

Table 5.25 Memory Expansion Mode and Microprocessor Mode (for 2- to 3-wait setting, external area access and multiplexed bus selection)

Symbol	Parameter	Measuring Condition	Standard		Unit
			Min.	Max.	
$t_{d(BCLK-AD)}$	Address output delay time	Figure 5.2		25	ns
$t_{h(BCLK-AD)}$	Address output hold time (in relation to BCLK)		4		ns
$t_{h(RD-AD)}$	Address output hold time (in relation to RD)		(NOTE 1)		ns
$t_{h(WR-AD)}$	Address output hold time (in relation to WR)		(NOTE 1)		ns
$t_{d(BCLK-CS)}$	Chip select output delay time			25	ns
$t_{h(BCLK-CS)}$	Chip select output hold time (in relation to BCLK)		4		ns
$t_{h(RD-CS)}$	Chip select output hold time (in relation to RD)		(NOTE 1)		ns
$t_{h(WR-CS)}$	Chip select output hold time (in relation to WR)		(NOTE 1)		ns
$t_{d(BCLK-RD)}$	RD signal output delay time			25	ns
$t_{h(BCLK-RD)}$	RD signal output hold time		0		ns
$t_{d(BCLK-WR)}$	WR signal output delay time			25	ns
$t_{h(BCLK-WR)}$	WR signal output hold time		0		ns
$t_{d(BCLK-DB)}$	Data output delay time (in relation to BCLK)			40	ns
$t_{h(BCLK-DB)}$	Data output hold time (in relation to BCLK)		4		ns
$t_{d(DB-WR)}$	Data output delay time (in relation to WR)		(NOTE 2)		ns
$t_{h(WR-DB)}$	Data output hold time (in relation to WR)		(NOTE 1)		ns
$t_{d(BCLK-HLDA)}$	$\overline{HLDA}$ output delay time			40	ns
$t_{d(BCLK-ALE)}$	ALE signal output delay time (in relation to BCLK)			15	ns
$t_{h(BCLK-ALE)}$	ALE signal output hold time (in relation to BCLK)		–4		ns
$t_{d(AD-ALE)}$	ALE signal output delay time (in relation to Address)		(NOTE 3)		ns
$t_{h(ALE-AD)}$	ALE signal output hold time (in relation to Address)		(NOTE 4)		ns
$t_{d(AD-RD)}$	RD signal output delay from the end of Address		0		ns
$t_{d(AD-WR)}$	WR signal output delay from the end of Address		0		ns
$t_{dZ(RD-AD)}$	Address output floating start time			8	ns

NOTES:

1. Calculated according to the BCLK frequency as follows:

$$\frac{0.5 \times 10^9}{f(BCLK)} - 10 \text{ [ns]}$$

2. Calculated according to the BCLK frequency as follows:

$$\frac{(n - 0.5) \times 10^9}{f(BCLK)} - 40 \text{ [ns]}$$

n is “2” for 2-wait setting, “3” for 3-wait setting.

3. Calculated according to the BCLK frequency as follows:

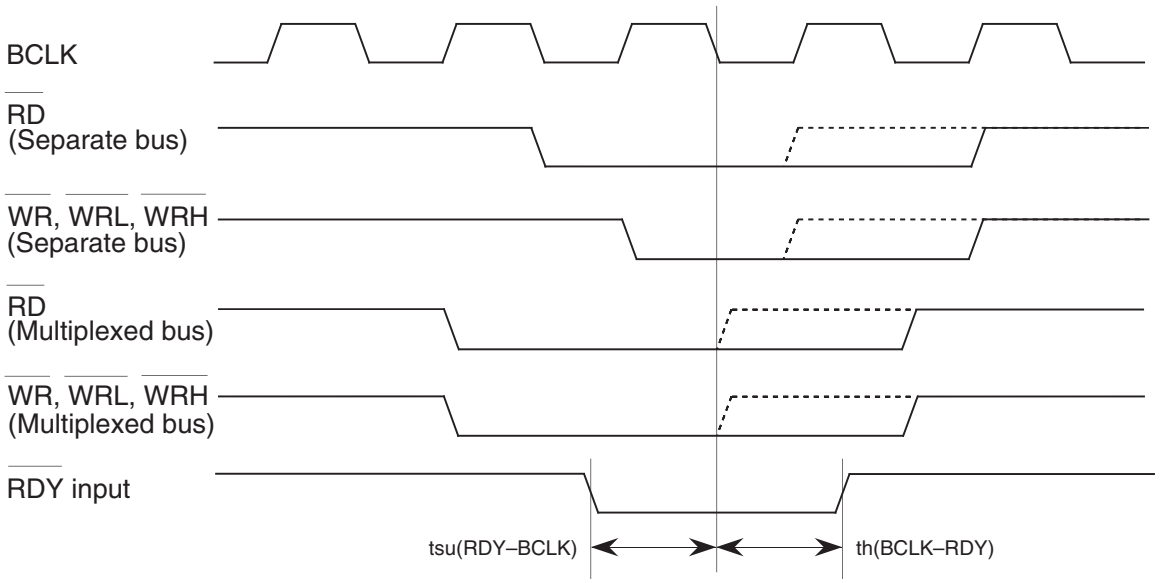
$$\frac{0.5 \times 10^9}{f(BCLK)} - 25 \text{ [ns]}$$

4. Calculated according to the BCLK frequency as follows:

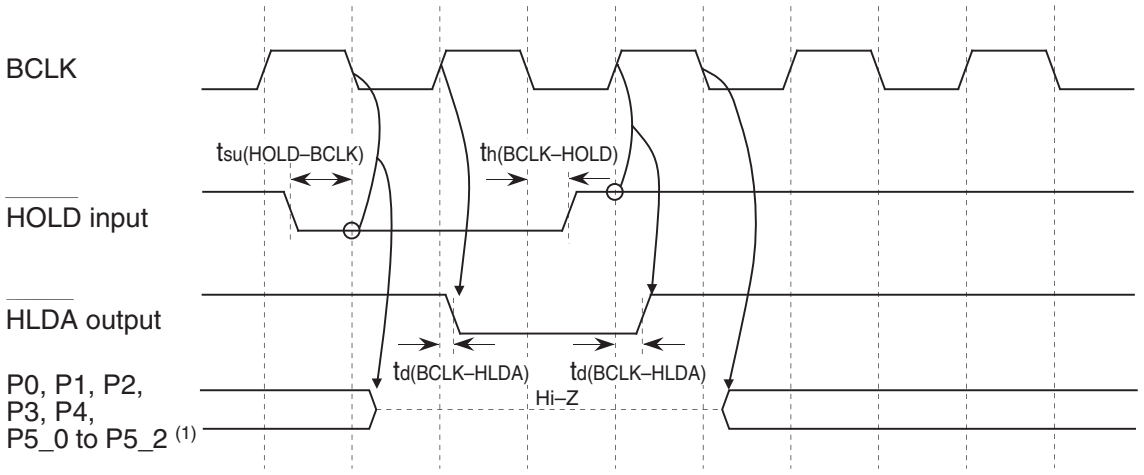
$$\frac{0.5 \times 10^9}{f(BCLK)} - 15 \text{ [ns]}$$

Memory Expansion Mode and Microprocessor Mode **VCC = 5 V**

(Effective for setting with wait)



(Common to setting with wait and setting without wait)



NOTE:
1. The above pins are set to high-impedance regardless of the input level of the BYTE pin, the PM06 bit in the PM0 register, and the PM11 bit in the PM1 register.

Measuring conditions :
- VCC = 5 V
- Input timing voltage : Determined with V_{IL} = 1.0 V, V_{IH} = 4.0 V
- Output timing voltage: Determined with V_{OL} = 2.5 V, V_{OH} = 2.5 V

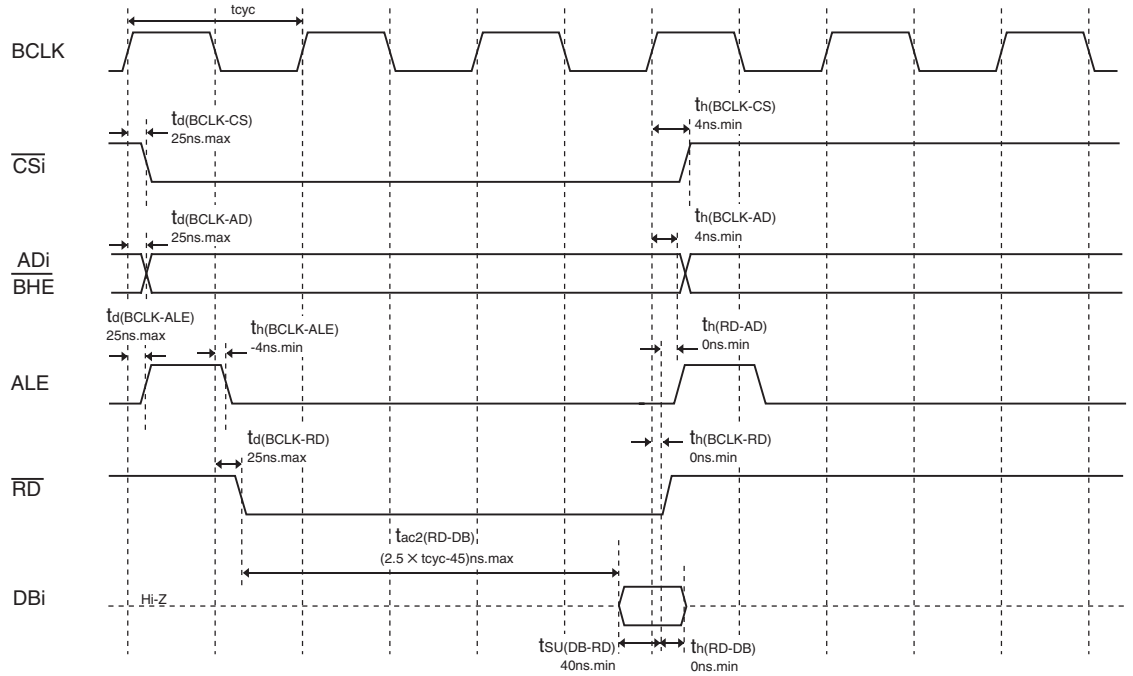
Figure 5.4 Timing Diagram (2)

Memory Expansion Mode and Microprocessor Mode

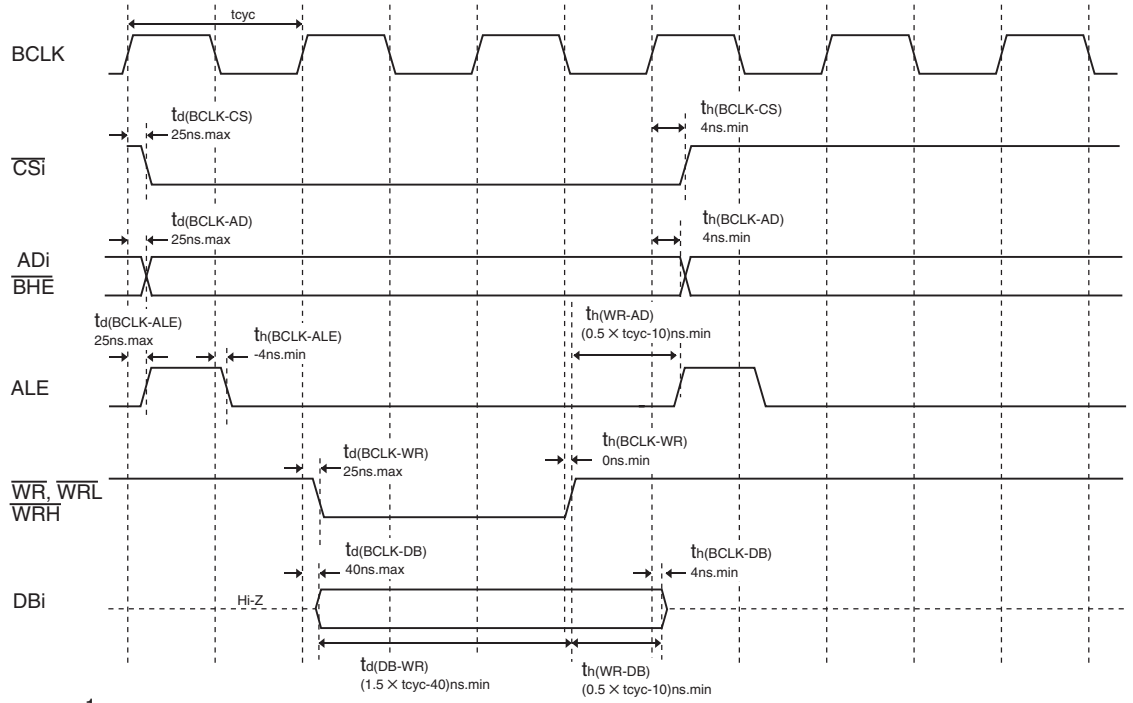
VCC = 5 V

(For 2-wait setting and external area access)

Read timing



Write timing



$$tcyc = \frac{1}{f(BCLK)}$$

Measuring conditions :

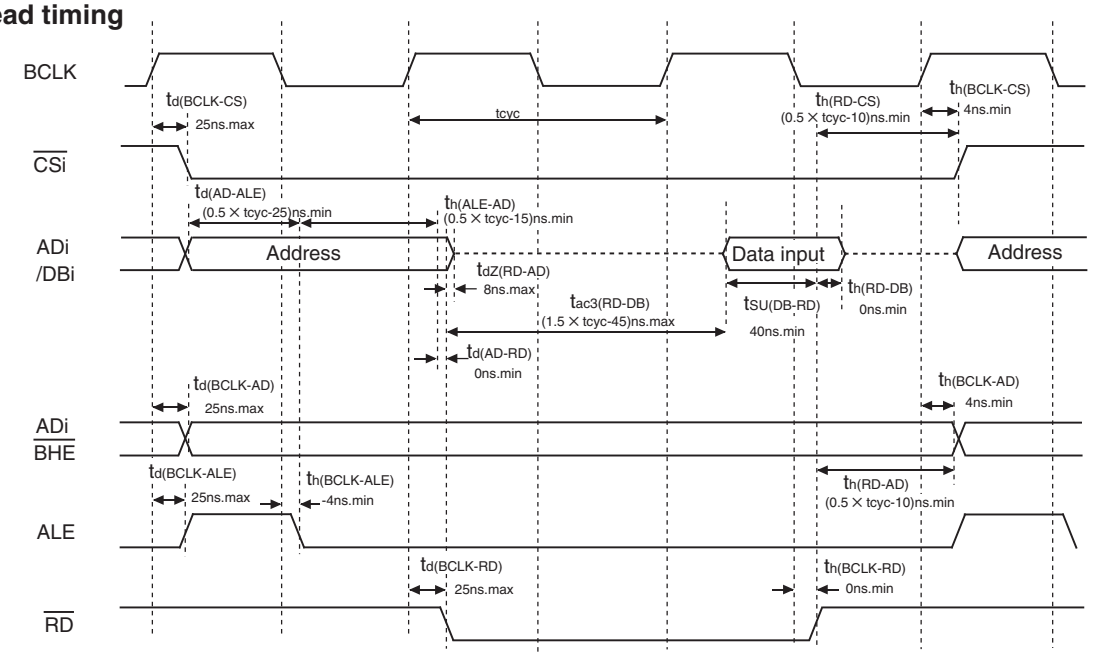
- VCC = 5 V
- Input timing voltage : V_{IL} = 0.8 V, V_{IH} = 2.0 V
- Output timing voltage : V_{OL} = 0.4 V, V_{OH} = 2.4 V

Figure 5.7 Timing Diagram (5)

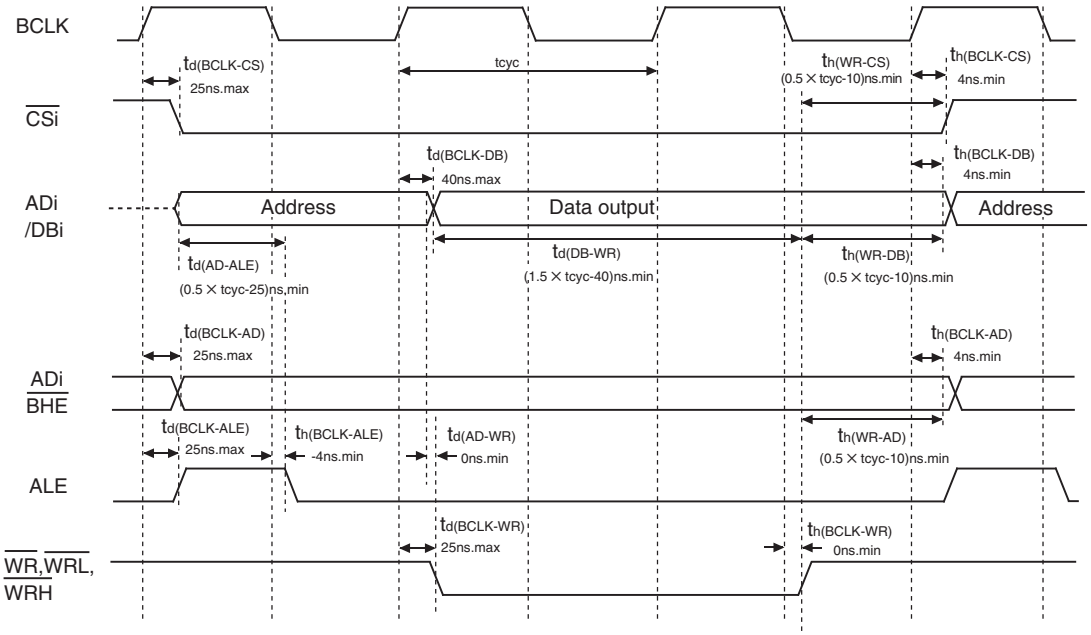
Memory Expansion Mode and Microprocessor Mode — VCC = 5 V

(For 1- or 2-wait setting, external area access and multiplexed bus selection)

Read timing



Write timing



$$tcyc = \frac{1}{f(BCLK)}$$

Measuring conditions :

- VCC = 5 V
- Input timing voltage : V_{IL} = 0.8 V, V_{IH} = 2.0 V
- Output timing voltage : V_{OL} = 0.4 V, V_{OH} = 2.4 V

Figure 5.9 Timing Diagram (7)

Switching Characteristics

VCC = 5 V

(Referenced to VCC = 5 V, VSS = 0 V, at Topr = –40 to 85 °C unless otherwise specified)

Table 5.48 Memory Expansion Mode and Microprocessor Mode (for setting with no wait)

Symbol	Parameter	Measuring Condition	Standard		Unit
			Min.	Max.	
$t_{d(BCLK-AD)}$	Address output delay time	Figure 5.12		25	ns
$t_{h(BCLK-AD)}$	Address output hold time (in relation to BCLK)		4		ns
$t_{h(RD-AD)}$	Address output hold time (in relation to RD)		0		ns
$t_{h(WR-AD)}$	Address output hold time (in relation to WR)		(NOTE 1)		ns
$t_{d(BCLK-CS)}$	Chip select output delay time			25	ns
$t_{h(BCLK-CS)}$	Chip select output hold time (in relation to BCLK)		4		ns
$t_{d(BCLK-ALE)}$	ALE signal output delay time			15	ns
$t_{h(BCLK-ALE)}$	ALE signal output hold time		–4		ns
$t_{d(BCLK-RD)}$	RD signal output delay time			25	ns
$t_{h(BCLK-RD)}$	RD signal output hold time		0		ns
$t_{d(BCLK-WR)}$	WR signal output delay time			25	ns
$t_{h(BCLK-WR)}$	WR signal output hold time		0		ns
$t_{d(BCLK-DB)}$	Data output delay time (in relation to BCLK)			40	ns
$t_{h(BCLK-DB)}$	Data output hold time (in relation to BCLK) (3)		4		ns
$t_{d(DB-WR)}$	Data output delay time (in relation to WR)		(NOTE 2)		ns
$t_{h(WR-DB)}$	Data output hold time (in relation to WR) (3)		(NOTE 1)		ns
$t_{d(BCLK-HLDA)}$	$\overline{HLDA}$ output delay time			40	ns

NOTES:

1. Calculated according to the BCLK frequency as follows:

$$\frac{0.5 \times 10^9}{f(BCLK)} - 10 \text{ [ns]}$$

2. Calculated according to the BCLK frequency as follows:

$$\frac{0.5 \times 10^9}{f(BCLK)} - 40 \text{ [ns]}$$ f(BCLK) is 12.5 MHz or less.

3. This standard value shows the timing when the output is off, and does not show hold time of data bus.
Hold time of data bus varies with capacitor volume and pull-up (pull-down) resistance value.
Hold time of data bus is expressed in
$t = -CR \times \ln (1 - V_{OL} / V_{CC})$
by a circuit of the right figure.
For example, when $V_{OL} = 0.2\ V_{CC}$, C = 30 pF, R =1 kΩ, hold time of output "L" level is
$t = -30\ pF \times 1\ k\Omega \times \ln (1 - 0.2\ V_{CC} / V_{CC}) = 6.7$ ns.

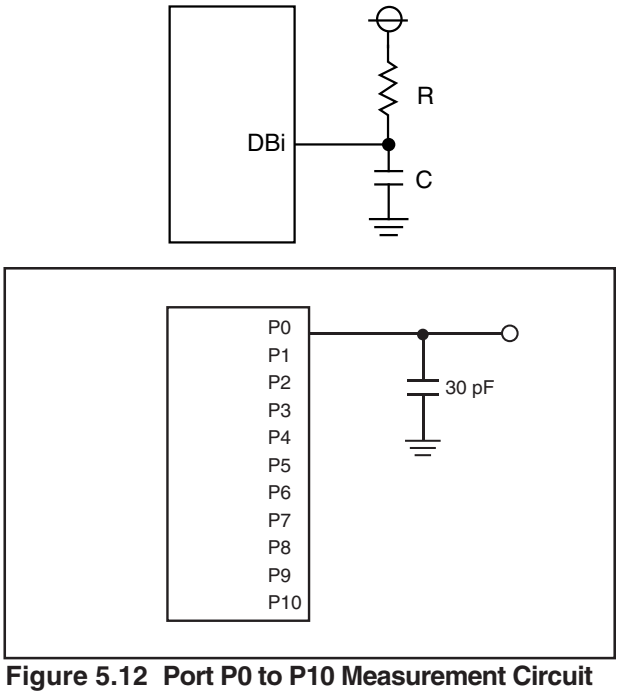


Figure 5.12 Port P0 to P10 Measurement Circuit

Timing Requirements **VCC = 3.3 V**

(Referenced to VCC = 3.3 V, VSS = 0 V, at Topr = –40 to 85°C unless otherwise specified)

Table 5.52 External Clock Input (XIN Input)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
t_c	External clock input cycle time	62.5		ns
$t_{w(H)}$	External clock input HIGH pulse width	25		ns
$t_{w(L)}$	External clock input LOW pulse width	25		ns
t_r	External clock rise time		15	ns
t_f	External clock fall time		15	ns

Table 5.53 Memory Expansion Mode and Microprocessor Mode

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{ac1(RD-DB)}$	Data input access time (for setting with no wait)		(NOTE 1)	ns
$t_{ac2(RD-DB)}$	Data input access time (for setting with wait)		(NOTE 2)	ns
$t_{ac3(RD-DB)}$	Data input access time (when accessing multiplexed bus area)		(NOTE 3)	ns
$t_{su(DB-RD)}$	Data input setup time	50		ns
$t_{su(RDY-BCLK)}$	$\overline{RDY}$ input setup time	40		ns
$t_{su(HOLD-BCLK)}$	$\overline{HOLD}$ input setup time	50		ns
$t_{h(RD-DB)}$	Data input hold time	0		ns
$t_{h(BCLK-RDY)}$	$\overline{RDY}$ input hold time	0		ns
$t_{h(BCLK-HOLD)}$	$\overline{HOLD}$ input hold time	0		ns

NOTES:

1. Calculated according to the BCLK frequency as follows:

$$\frac{0.5 \times 10^9}{f(BCLK)} - 60 \text{ [ns]}$$

2. Calculated according to the BCLK frequency as follows:

$$\frac{(n - 0.5) \times 10^9}{f(BCLK)} - 60 \text{ [ns]}$$ n is “2” for 1-wait setting, “3” for 2-wait setting and “4” for 3-wait setting.

3. Calculated according to the BCLK frequency as follows:

$$\frac{(n - 0.5) \times 10^9}{f(BCLK)} - 60 \text{ [ns]}$$ n is “2” for 2-wait setting, “3” for 3-wait setting.

Timing Requirements

VCC = 3.3 V

(Referenced to VCC = 3.3 V, VSS = 0 V, at Topr = –40 to 85°C unless otherwise specified)

Table 5.60 Timer B Input (Counter Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN input cycle time (counted on one edge)	150		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width (counted on one edge)	60		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width (counted on one edge)	60		ns
$t_{c(TB)}$	TBiIN input cycle time (counted on both edges)	300		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width (counted on both edges)	120		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width (counted on both edges)	120		ns

Table 5.61 Timer B Input (Pulse Period Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN input cycle time	600		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width	300		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width	300		ns

Table 5.62 Timer B Input (Pulse Width Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN input cycle time	600		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width	300		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width	300		ns

Table 5.63 A/D Trigger Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(AD)}$	$\overline{\text{ADTRG}}$ input cycle time (trigger able minimum)	1500		ns
$t_{w(ADL)}$	$\overline{\text{ADTRG}}$ input LOW pulse width	200		ns

Table 5.64 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi input cycle time	300		ns
$t_{w(CKH)}$	CLKi input HIGH pulse width	150		ns
$t_{w(CKL)}$	CLKi input LOW pulse width	150		ns
$t_{d(C-Q)}$	TXDi output delay time		160	ns
$t_{h(C-Q)}$	TXDi hold time	0		ns
$t_{su(D-C)}$	RXDi input setup time	100		ns
$t_{h(C-D)}$	RXDi input hold time	90		ns

Table 5.65 External Interrupt $\overline{\text{INTi}}$ Input

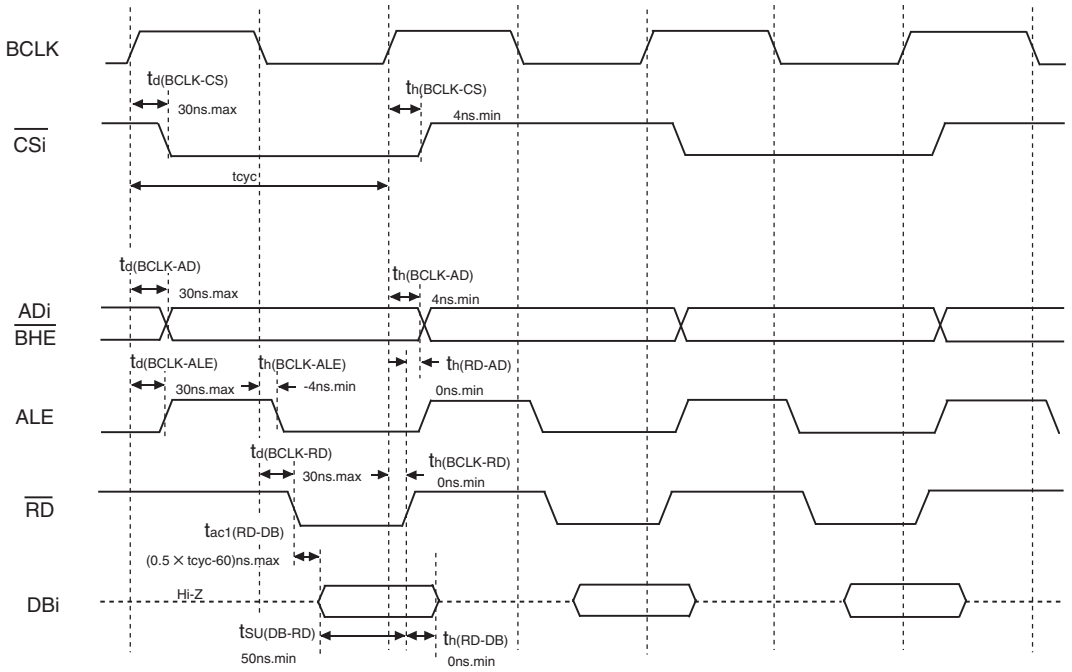
Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	$\overline{\text{INTi}}$ input HIGH pulse width	380		ns
$t_{w(INL)}$	$\overline{\text{INTi}}$ input LOW pulse width	380		ns

Memory Expansion Mode and Microprocessor Mode

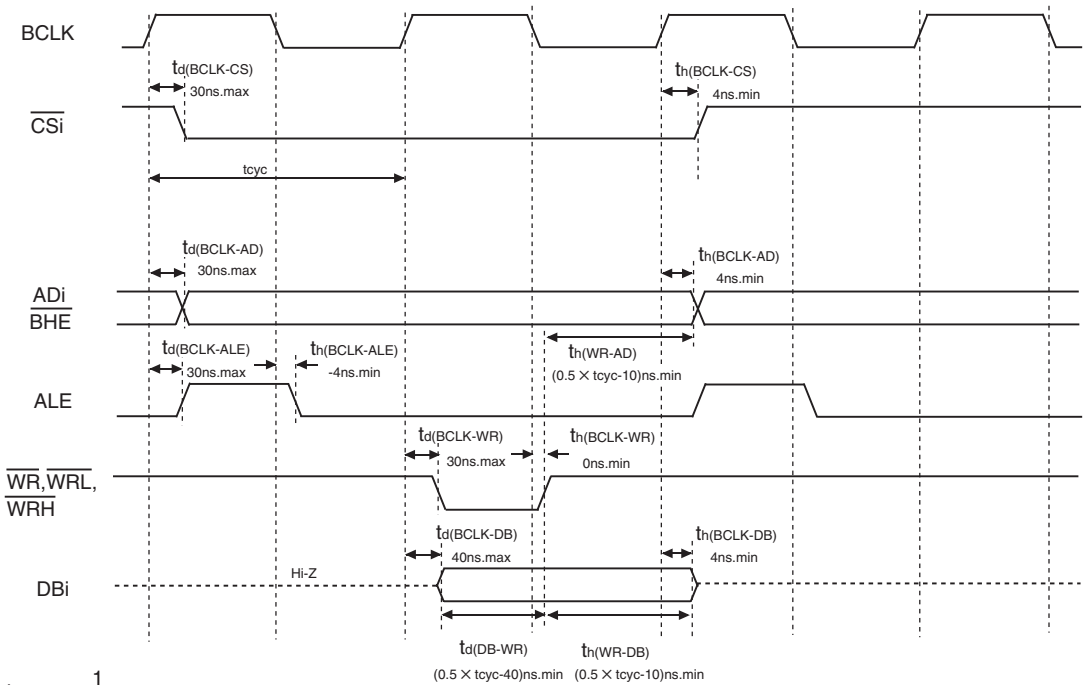
VCC = 3.3 V

(For setting with no wait)

Read timing



Write timing



$$tcyc = \frac{1}{f(BCLK)}$$

Measuring conditions :

- VCC = 3.3 V
- Input timing voltage : V_{IL} = 0.6 V, V_{IH} = 2.7 V
- Output timing voltage : V_{OL} = 1.65 V, V_{OH} = 1.65 V

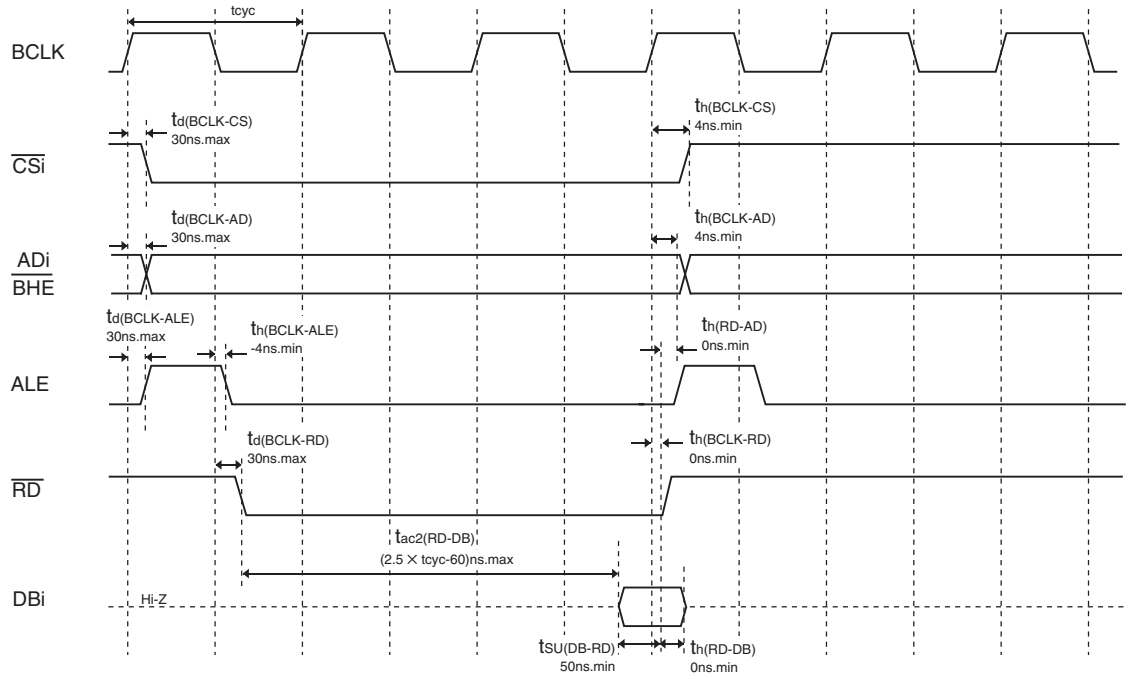
Figure 5.24 Timing Diagram (3)

Memory Expansion Mode and Microprocessor Mode

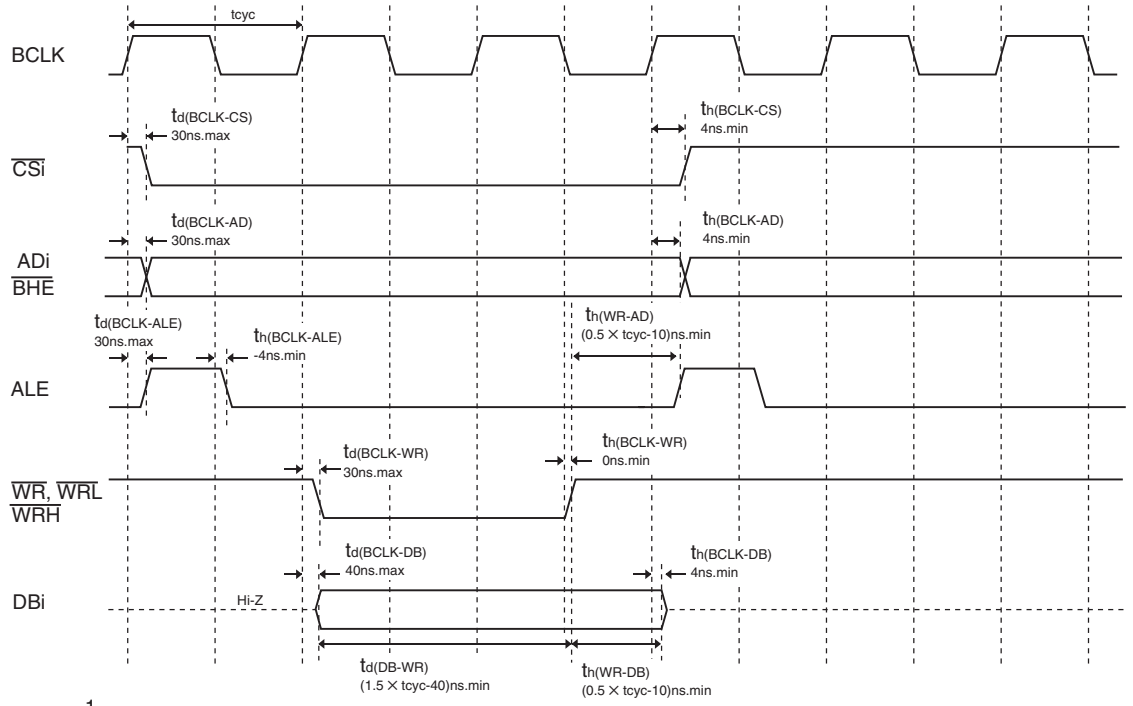
VCC = 3.3 V

(For 2-wait setting and external area access)

Read timing



Write timing



$$tcyc = \frac{1}{f(BCLK)}$$

Measuring conditions :

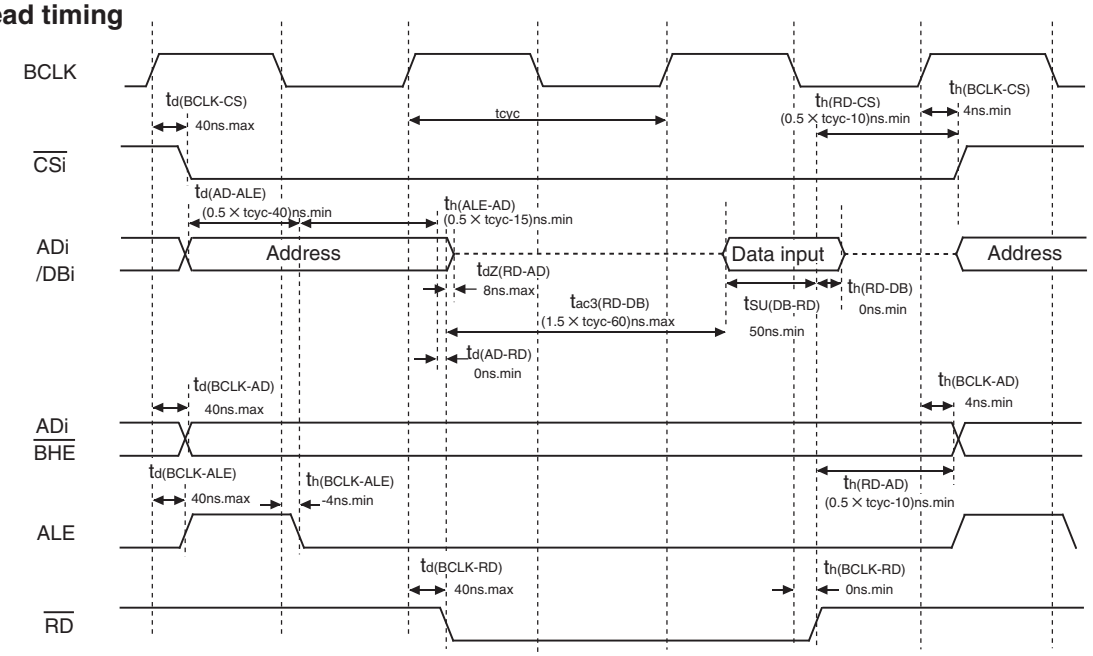
- VCC = 3.3 V
- Input timing voltage : V_{IL} = 0.6 V, V_{IH} = 2.7 V
- Output timing voltage : V_{OL} = 1.65 V, V_{OH} = 1.65 V

Figure 5.26 Timing Diagram (5)

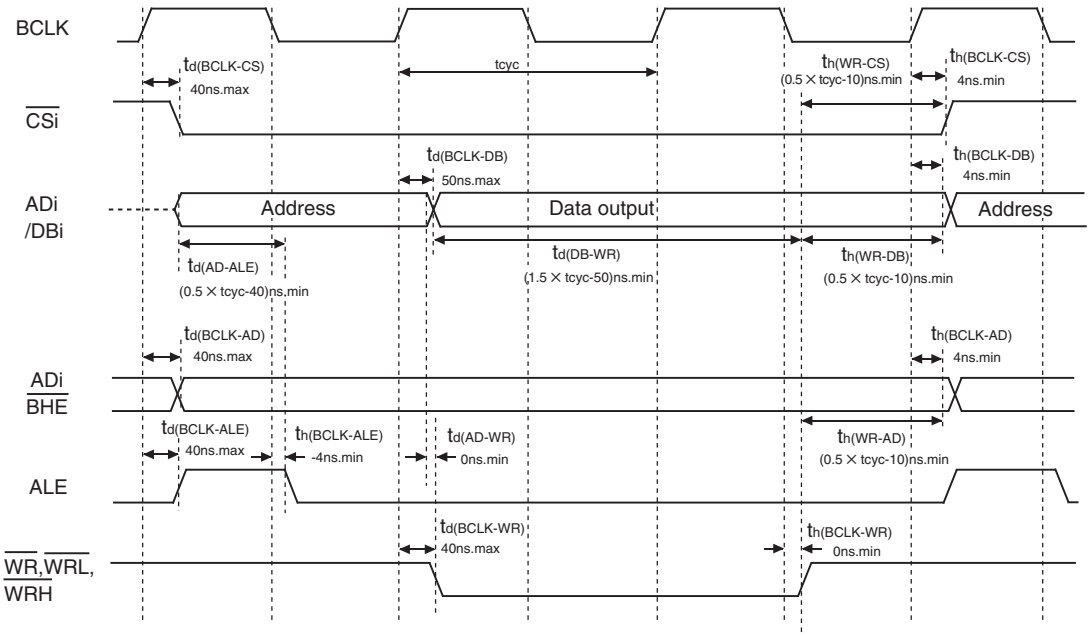
Memory Expansion Mode and Microprocessor Mode — VCC = 3.3 V

(For 2-wait setting, external area access and multiplexed bus selection)

Read timing



Write timing



$$tcyc = \frac{1}{f(BCLK)}$$

Measuring conditions :

- VCC = 3.3 V
- Input timing voltage : V_{IL} = 0.6 V, V_{IH} = 2.7 V
- Output timing voltage : V_{OL} = 1.65 V, V_{OH} = 1.65 V

Figure 5.28 Timing Diagram (7)